
HVU314

Variable Capacitance Diode for BS tuner

HITACHI

ADE-208-071C (Z)
Rev. 3

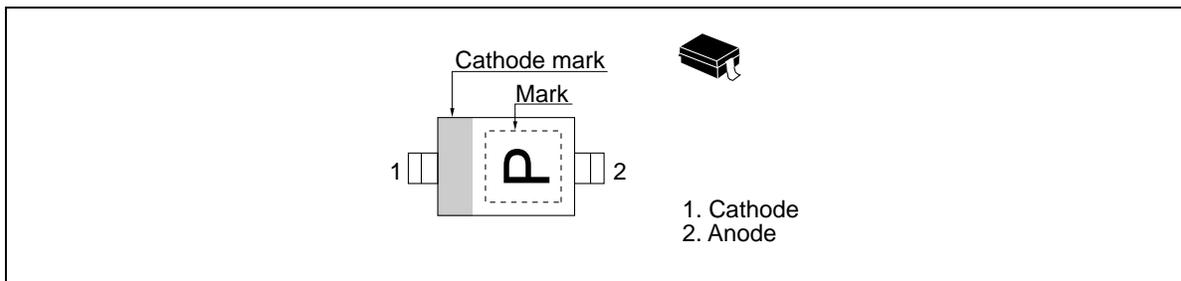
Features

- Low series resistance. ($r_s = 1.05\Omega_{\text{max}}$)
- Ultra small Resin Package (URP) is suitable for surface mount design.

Ordering Information

Type No.	Laser Mark	Package Code
HVU314	P	URP

Outline



HVU314

Absolute Maximum Ratings (Ta = 25°C)

Item	Symbol	Value	Unit
Reverse voltage	V_R	32	V
Junction temperature	T_j	125	°C
Storage temperature	T_{stg}	-55 to +125	°C

Electrical Characteristics (Ta = 25°C)

Item	Symbol	Min	Typ	Max	Unit	Test Condition
Reverse current	I_{R1}	—	—	10	nA	$V_R = 32V$
	I_{R2}	—	—	100		$V_R = 32V, T_a = 60°C$
Capacitance	C_1	4.40	—	6.40	pF	$V_R = 1V, f = 1MHz$
	C_{10}	0.86	—	1.35		$V_R = 10V, f = 1MHz$
	C_{30}	0.47	—	0.73		$V_R = 30V, f = 1MHz$
Capacitance ratio	n	7.0	—	—	—	C_1/C_{30}
Series resistance	r_s	—	—	1.05	Ω	$V_R = 5V, f = 470MHz$
Matching error	$\Delta C/C^{*1}$	—	—	6.0	%	$V_R = 1$ to $30V$

Notes: 1. A set of HVU314 is of uniform C-V characteristics.

Measure max. value and min. value of capacitance at each bias point of $V_R = 1V$ through $30V$.

Calculate Matching Error, $\Delta C/C = \frac{(C_{max} - C_{min})}{C_{min}} \times 100$ (%)

2. Each group shall uniform a multiple of 4 diodes.

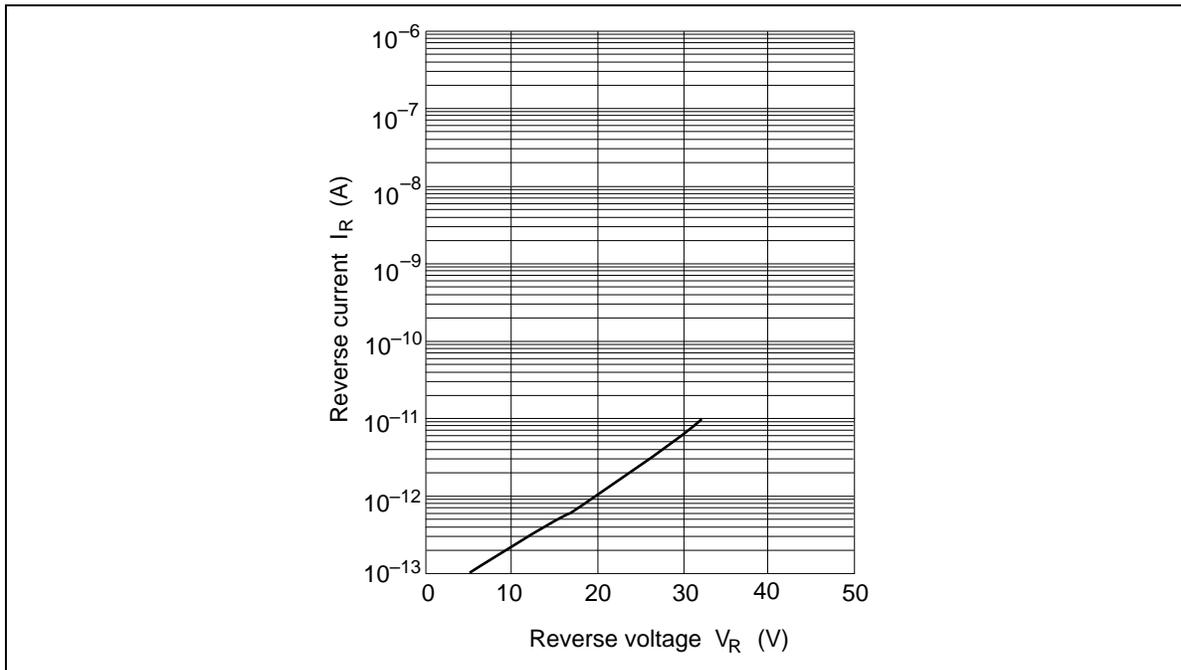


Fig.1 Reverse current Vs. Reverse voltage

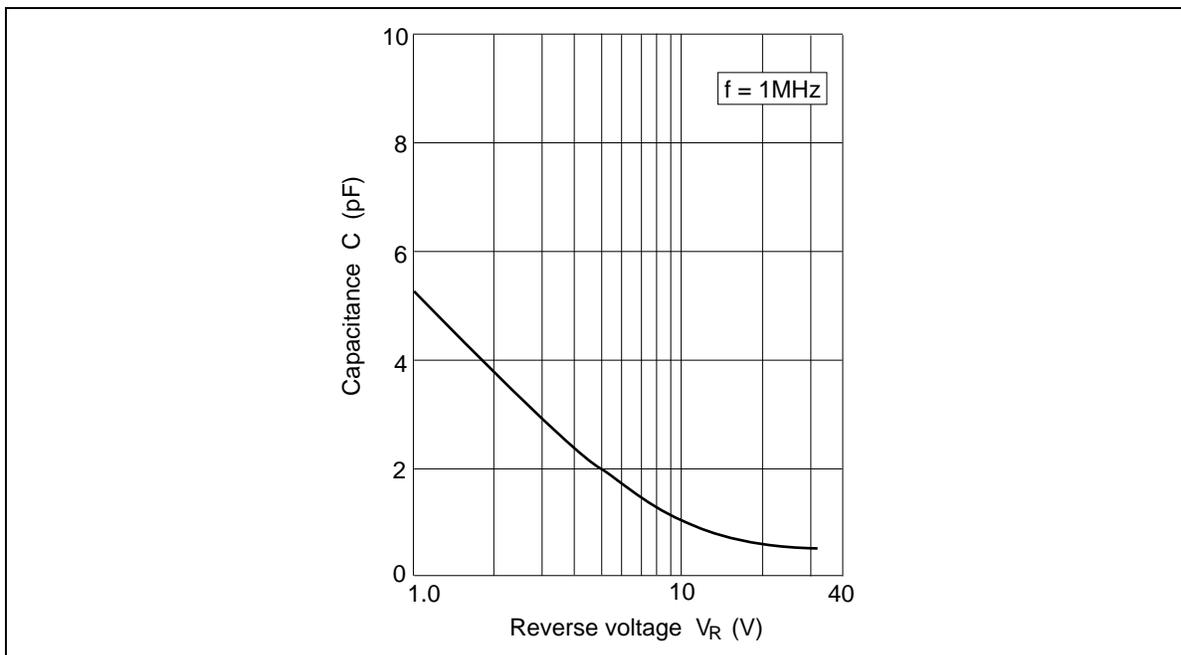


Fig.2 Capacitance Vs. Reverse voltage

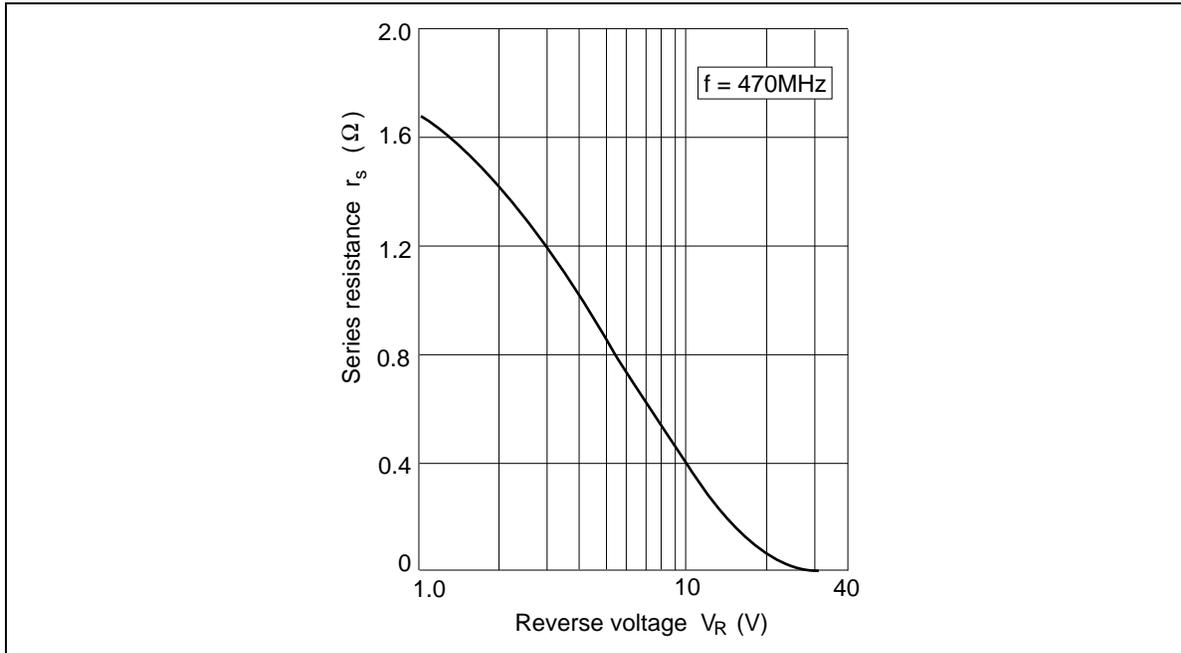


Fig.3 Series resistance Vs. Reverse voltage

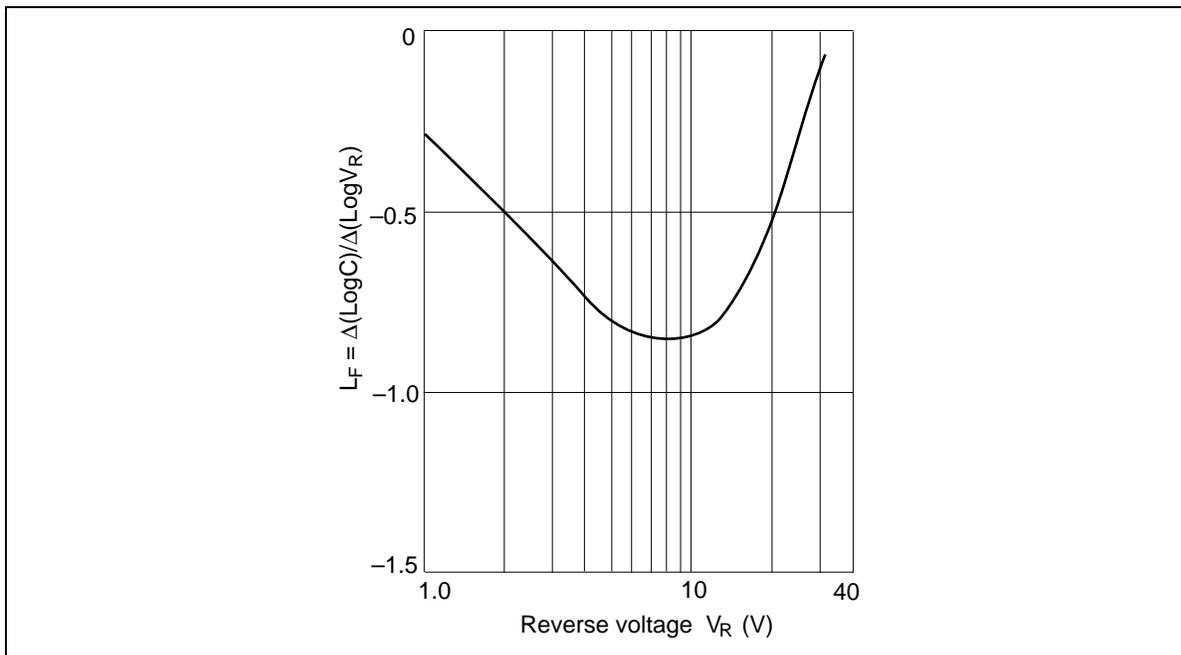


Fig.4 Linearity factor Vs. Reverse voltage

Package Dimensions

